

13-MEMORY TONE/PULSE DIALER WITH HANDFREE AND HOLD FUNCTIONS

GENERAL DESCRIPTION

The W91350N series are tone/pluse switchable telephone dialers with thirteen memories, hold function, and a handfree dialing control circuit. Fabricated using CMOS technology, the W91350N series offer good performance in low-voltage and low-power applications.

FEATURES

- · DTMF/pulse switchable dialer
- Two by 32-digit redial memory and save memory
- Three by 16-digit one-touch direct repertory memory
- Ten by 16-digit two-touch direct repertory memory
- Cascaded dialing allowed, with unlimited dialing length
- Pulse-to-tone (*/T) keypad for long distance call operation
- Uses 5 × 5 keyboard
- Easy operation with redial, flash, pause, and */T keypads
- Pause, P→T (pulse-to-tone) can be stored as a digit in memory
- Dialing rate (10 ppS or 20 ppS) is selectable by bonding option
- On-hook debounce time: 150 msec.
- Minimum tone output duration: 93 msec. (W91354AN: 87 mS)
- Minimum intertone pause: 93 msec. (W91354AN: 87 mS)
- Flash break time (73, 100, 300, 600 msec) selectable by keypad; pause time is 1.0 sec.
- Make/break ratio (40:60 or 33.3:66.7) selectable by MODE pin
- · On-chip power-on reset
- Uses 3.579545 MHz crystal or ceramic resonator
- · Packaged in 18 or 20-pin plastic DIP
- The different dialers in the W91350N series are shown in the following table:

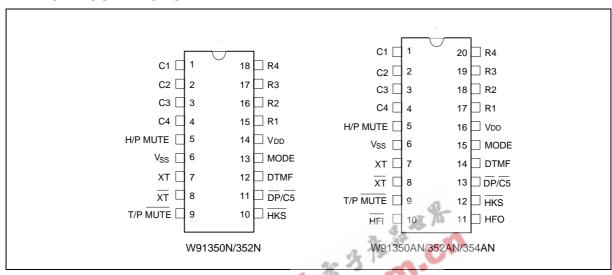
TYPE NO.	REPLACEMENT TYPE NO.	PULSE (ppS)	FLASH (mS)	M/B	HANDFREE DIALING	PACKAGE (PINS)
W91350N	W91350	10	600/300/73/100	Pin	-	18
	W91351					
W91352N	W91352	20	600/300/73/100	Pin	-	18
W91350AN	W91350A	10	600/300/73/100	Pin	Yes	20
	W91351A					
W91352AN	W91352A	20	600/300/73/100	Pin	Yes	20
W91354AN	New type	10	600/300/73/100	Pin	Yes	20

Note: The W91354AN is for use in France only. The pause time is not added in pulse-to-tone function mode.

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PIN CONFIGURATIONS



PIN DESCRIPTION

			_	
SYMBOL	18-PIN	20-PIN	1/0	FUNCTION
Column- Row Inputs	1–4 & 15–18	1–4 & 17–20		The keyboard inputs may be used with either a standard 5×5 keyboard or an inexpensive single contact (Form A) keyboard. Electronic input from a μ C can also be used. A valid key in is defined as a single row being connected to a single column.
XT, XT	7, 8	7, 8	I, O	A built-in inverter provides oscillation with an inexpensive 3.579545 MHz crystal or ceramic resonator.
T/P MUTE	9	9	0	The T/P MUTE is a conventional CMOS N-channel open drain output. The output transistor is switched on during dialing sequence and flash break time. Otherwise, it is switched off.
MODE	13	15	I	Pulling mode pin to Vss places the dialer in tone mode. Pulling mode pin to VDD places the dialer in pulse mode with M/B ratio of 40:60 (10 ppS, except for W91352N/352AN = 20 ppS). Floating mode pin places the dialer in pulse mode with M/B ratio of 33.3:66.7 (10 ppS, except for W91352N/352AN = 20 ppS).
HKS	10	12	I	Hook switch input. HKS = VDD: On-hook state. Chip in sleeping mode, no operation. HKS = Vss: Off-hook state. Chip is enabled for normal operation. HKS pin is pulled to VDD by an internal resistor.



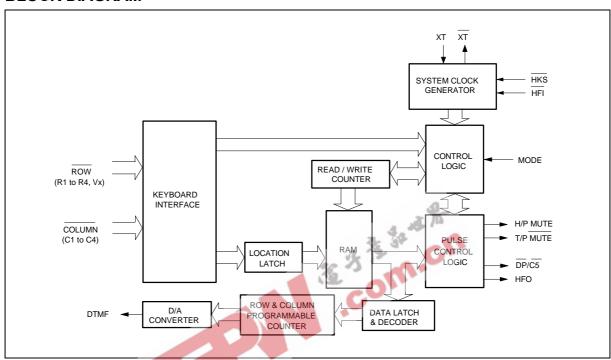
Pin Description, continued

SYMBOL	18-PIN	20-PIN	I/O			FUNCT	ION			
DP/C5	11	13	0	Flash key will	N-channel open drain dialing pulse output. Flash key will cause $\overline{DP}/\overline{C5}$ to be active in either tone mode or pulse mode.					
				The timing diag	ram for	pulse mode	is sho	wn in Figu	re 1(a, b, c).	
VDD, VSS	14, 6	16, 6	I	Power input pi	ns.					
DTMF	12	14	0	In tone mode,	In pulse mode, this pin remains in low state at all times. In tone mode, it will output a dual or single tone. Detailed timing diagram for tone mode is shown in Figure 2(a, b, c).					
				Out	put Frequ	iency	9			
				Specified	d Act	uai Erro	r %			
				R1 697	69					
				R2 770	76					
				R3 852	84	8 -0.4	7			
				R4 941	94	8 +0.7	' 4			
				C1 1209	12	16 +0.5	57			
				C2 1336	13	32 -0.3	0			
				C3 1477	14	72 -0.3	4			
HFI, HFO	-	10, 11	I, O	Handfree cont on by a low pu handfree contr	lse on the	ne HFI inpo is describe	ut pin. • ed in th	The status	of the	
				CURRENT STA	TE	NEXT S	TATE			
				Hook SW.	HFO	Input	HFO	Dialing		
				_	Low	HFI ↓	High	Yes		
				On Hook	High	HFI <u>↓</u>	Low	No		
				Off Hook	High	HFI <u>↓</u>	Low	Yes		
				On Hook	-	Off Hook	Low	Yes		
				Off Hook	Low	On Hook	Low	No		
				Off Hook	High	On Hook	High	Yes		
				HFI pin is pulled Detailed timing						
H/P MUTE	5	5	0	The H/P MUTI pulse dialing, figh; otherwise	lash bre	ak or hold	period			

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BLOCK DIAGRAM



FUNCTIONAL DESCRIPTION

Keyboard Operation

C1	C2	C3	C4	DP/C5	
1	2	3	S	M1	R1
4	5	6	F4	M2	R2
7	8	9	Α	М3	R3
*/T	0	#	R/P	SAVE	R4
F1	F2	F3	Н		Vx

- S: Store function key
- H: Hold function key
- A: Indirect repertory memory dialing function key
- R/P: Redial and pause function key
- · SAVE: Save function key
- */T: * in tone mode and P→T in pulse mode
- M1, ..., M3: One-touch memory
- F1, ..., F4: Flash keys, F1 = 600 mS, F2 = 300 mS, F3 = 73 mS, F4 = 100 mS

Notes:

D1, ..., Dn, D1', ..., Dn': 0, ..., 9, */T, # Mn: M1, ..., M3; Ln: 0, ..., 9; Fn: F1, ..., F4





Normal Dialing

OFF HOOK , (or ON HOOK &
$$\overline{\text{HFI }}\overline{\text{i}}\overline{\text{o}}$$
), D1 , D2 , Dn

- 1. D1, D2, ..., Dn will be dialed out.
- 2. Dialing length is unlimited, but redial is inhibited if length exceeds 32 digits in normal dialing.

Redialing

- 1. The redial memory content will be dialed out.
- 2. The R/P key can execute the redial function only as the first key-in after off-hook; otherwise, it executes pause function.
- 3. If redialing length exceeds 32 digits, the redialing function will be inhibited.

Number Store

- 1. If the sequence of the dialed digits D1, D2, ..., Dn has not S will be ignored. finished,
- 2. D1, D2, ..., Dn will be dialed out and stored in memory location.

- 3. D1, D2, ..., Dn will be stored in memory location but will not be dialed out.
- 4. R/P and */T keys can be stored as a digit in memory.

In store mode, $\begin{tabular}{|c|c|c|c|c|c|c|}\hline R/P & is the pause function key. \\ \end{tabular}$

5. The store mode is released after the store function is executed or when the state of the hook switch changes.

Repertory Dialing

OFF HOOK , (or ON HOOK &
$$\overline{\text{HFI }} \overline{\text{i}} \overline{\text{o}}$$
), Mn OFF HOOK , (or ON HOOK & $\overline{\text{HFI }} \overline{\text{i}} \overline{\text{o}}$), A , Ln

Access Pause



- 1. The pause function can be stored as a digit in memory.
- 2. The pause function is executed in normal dialing, redial dialing, or memory dialing.
- 3. A detailed timing diagram for the pause function is shown in Figure 4.

Pulse-to-tone (*/T)

OFF HOOK , (or ON HOOK &
$$\overline{\text{HFI }\overline{\text{i}}\underline{\tilde{\text{o}}}}$$
), D1 , D2 , ..., Dn , */T , D1' , D2' , ..., Dn'

1. If the mode switch is set to pulse mode, then the output signal will be:

The pause time will be added in all versions except for the W91354AN

2. If the mode switch is set to tone mode, then the output signal will be:

- 3. The dialer remains in tone mode when the digits have been dialed out and can be reset to pulse mode only by going on-hook.
- 4. The pulse-to-tone function timing diagram is shown in Figure 5(a, b).

Flash

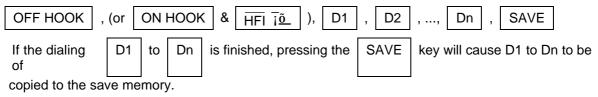
OFF HOOK , (or ON HOOK &
$$\overline{\text{HFI }}\overline{\text{i}}\underline{\tilde{\textbf{o}}}$$
), Fn

- 1. Fn = F1, ..., F4
- 2. The dialer will execute a flash break time of 600 mS (F1), 300 mS (F2), 73 mS (F3), or 100 mS (F4).

In each case the flash pause time is 1.0 sec. before the next digit is dialed out.

- 3. Flash key cannot be stored as a digit in memory, and it has first priority among keyboard functions.
- 4. The system will return to the initial state after the flash pause time is finished.
- 5. The flash function timing diagram is shown in Figure 6.

Save



Cascaded Dialing



3. Redialing + Normal Dialing + Repertory Dialing Redialing and save dialing are valid as first key-in only.

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
DC Supply Voltage	VDD-VSS	-0.3 to +7.0	V
	VIL	Vss -0.3	V
Input/Output Voltage	VIH	VDD +0.3	V
	Vol	Vss -0.3	V
	Voн	VDD +0.3	٧
Power Dissipation	PD	120	mW
Operation Temperature	Topr	-20 to +70	°C
Storage Temperature	Tstg	-55 to +150	°C

Note: Exposure to conditions beyond those listed under Absolute Maximum Ratings may adversely affect the life and reliability of the device.

DC CHARACTERISTICS

(VDD-Vss = 2.5V, Fosc. = 3.579545 MHz, TA = 25° C, All outputs unloaded)

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Operating Voltage	VDD	•	2.0	-	5.5	V
Operating Current	ЮР	Tone, Unloaded	ı	0.4	0.6	mA
		Pulse, Unloaded	ı	0.2	0.4	
Standby Current	ISB	HKS = Vss, No load & No key entry	1	-	15	μΑ
Memory Retention Current	IMR	HKS = VDD, VDD = 1.0V	1	-	0.2	μΑ
DTMF Output Voltage	Vто	Row group, RL = 5 K Ω	130	150	170	mVrm s
Pre-emphasis	-	Col/Row, VDD = 2.0 to 5.5V	1	2	3	dB
DTMF Distortion	THD	$RL = 5 K\Omega$, VDD = 2.0 to 5.5 V	-	-30	-23	dB
DTMF Output DC Level	VTDC	$RL = 5 K\Omega$, VDD = 2.0 to 5.5 V	1.0	-	3.0	٧
DTMF Output Sink Current	lτι	VTO = 0.5V	0.2	-	-	mA
DP Output Sink Current	IPL	VPO = 0.5V	0.5	-	-	mA

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T/P MUTE Output Sink Current	IML	VMO = 0.5V	0.5	-	-	mA
H/P Mute Output	Інрн	VHPH = 2.0V	0.5	-	-	mA
Drive/Sink Current	IHPL	VHPL = 0.5V	0.5	ı	ı	mΑ

DC Characteristics, continued

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT
HFO Drive/Sink Current	IHFH	VHFH = 2.0V	0.5	1	-	mA
	IHFL	VHFL = 0.5V	0.5	-	-	mA
Keypad Input Drive Current	IKD	VI = 0.0V	30	-	-	μΑ
Keypad Input Sink Current	lks	VI = 2.5V	200	400	-	μΑ
HKS I/P Pull-high Resistor	Rнк	-	在一个	300	-	ΚΩ
Keypad Resistance	Rĸ	- 3. 3		-	5.0	ΚΩ

Keypad Resistance	Rĸ				5.0	KΩ				
AC CHARACTERISTICS (VDD-Vss = 2.5V, Fosc. = 3.579545 MHz, Ta = 25° C, All outputs unloaded)										
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT				
Key-in Debounce	TKID	-	_	20	-	mS				
Key Release Debounce	TKRD	-	-	20	-	mS				
On-hook Debounce	TOHD	-	-	150	-	mS				
Pre-digit Pause ¹	TPDP1	Mode = VDD	-	40	-	mS				
	10 ppS	Mode = Floating	-	33.3	-					
Pre-digit Pause ²	TPDP2	Mode = VDD	-	20	-	mS				
	20 ppS	Mode = Floating	-	16.7	-					
Interdigit Pause	TIDP	10 ppS	-	800	-	mS				
(Auto Dialing)		20 ppS	-	500	-					
Make/Break Ratio	M/B	Mode = VDD	-	40:60	-	%				
		Mode = Floating	-	33.3:66.7	-					
Tone Output Duration	TTD	Auto dialing	-	93	-	mS				
		W91354AN Only	-	87	-					
Intertone Pause	TITP	Auto dialing	-	93	-	mS				
		W91354AN Only	-	87	-					
		F1	-	600	-					
Flash Break Time	Тғв	F2	-	300	-	mS				
		F3		73						
		F4	-	100	-					



Flash Pause Time	TFP	F1, F2, F3, F4	-	1.0	-	S
Pause Time	ТР	R/P	-	3.6	-	S

Notes:

- 1. Crystal parameters suggested for proper operation are Rs<100 ohms, Lm = 96 mH, Cm = 0.02 pF, Cn = 5 pF, Cl = 18 pF, Fosc.= 3.579545 MHz $\pm 0.02\%$.
- 2. Crystal oscillator accuracy directly affects these times.



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TIMING WAVEFORMS

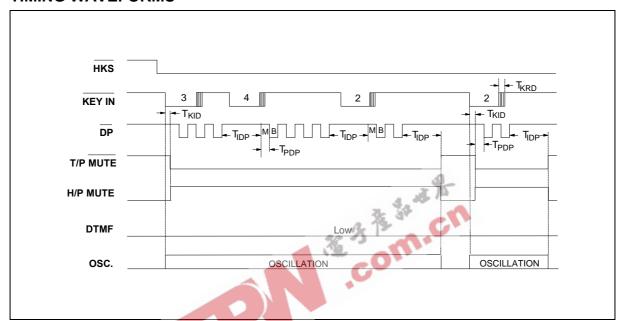


Figure 1(a). Normal Dialing Timing Diagram

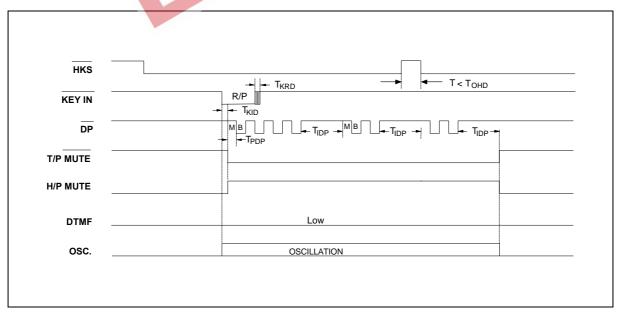


Figure 1(b) Pulse Mode Auto Dialing Timing Diagram



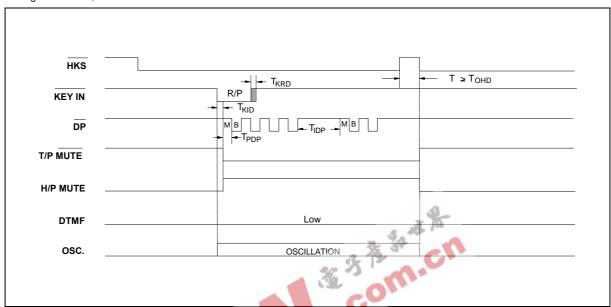


Figure 1(c) Pulse Mode Auto Dialing Timing Diagram

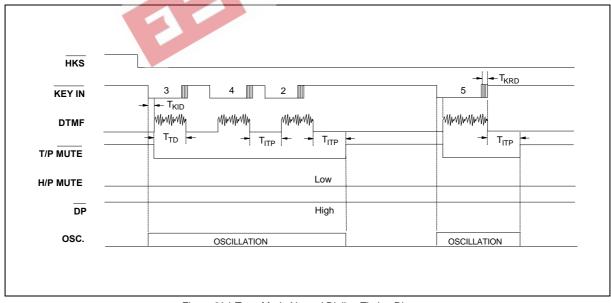


Figure 2(a) Tone Mode Normal Dialing Timing Diagram



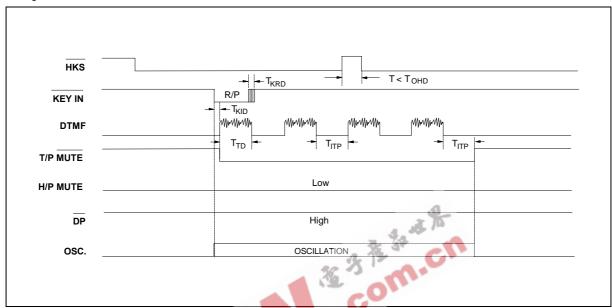


Figure 2(b) Tone Mode Auto Dialing Timing Diagram

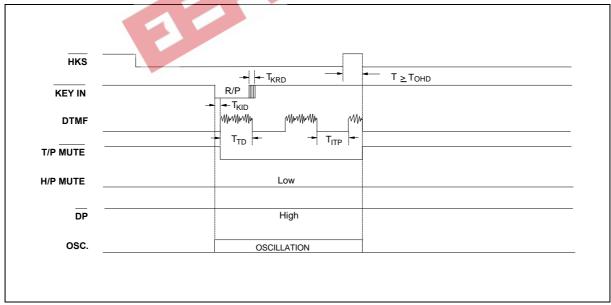


Figure 2(c) Tone Mode Auto Dialing Timing Diagram



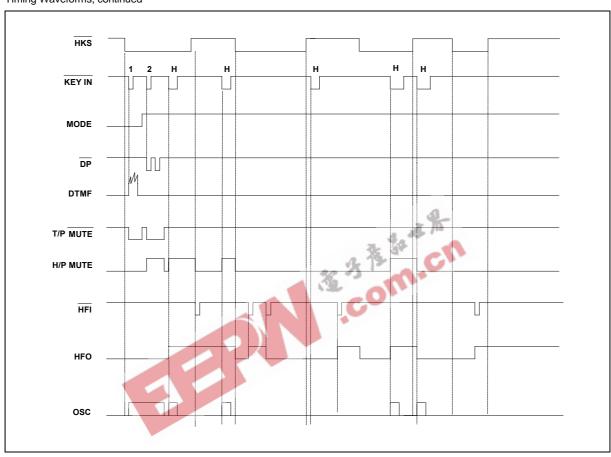


Figure 3. Handfree Function Timing Diagram

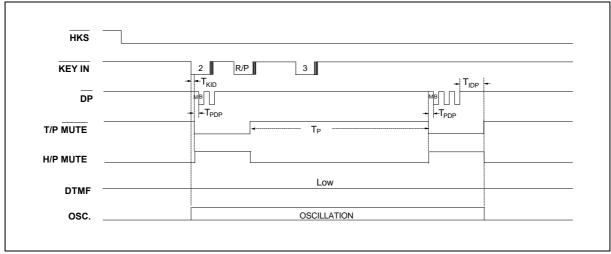


Figure 4. Pause Function Timing Diagram



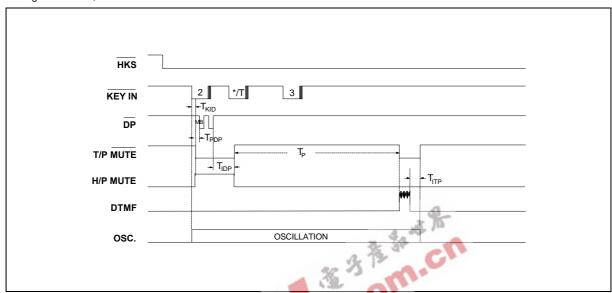


Figure 5(a). Pulse-to-tone Timing Diagram (All Versions Except W91354AN)

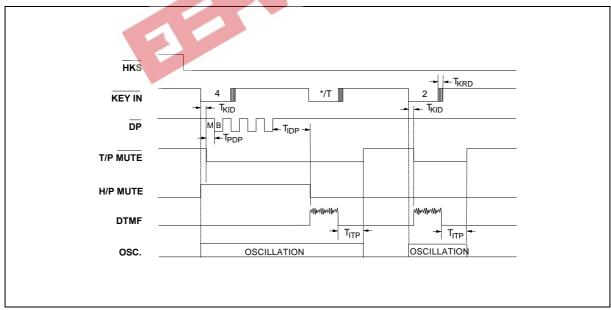


Figure 5(b). Pulse-to-tone Timing Diagram (W91354AN Only)



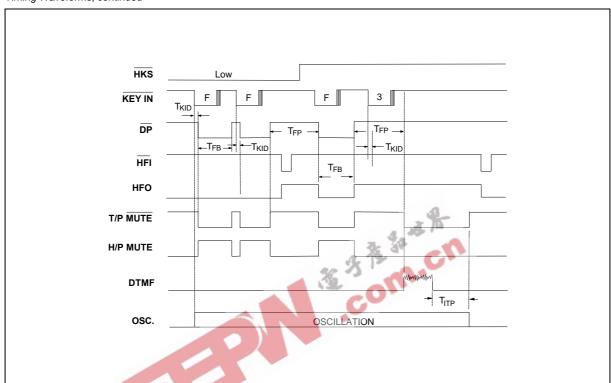


Figure 6. Flash Timing Diagram







Headquarters

No. 4, Creation Rd. III, Science-Based Industrial Park, Hsinchu, Taiwan TEL: 886-3-5770066 FAX: 886-3-5792697

http://www.winbond.com.tw/ Voice & Fax-on-demand: 886-2-7197006

Taipei Office

11F, No. 115, Sec. 3, Min-Sheng East Rd., Taipei, Taiwan TEL: 886-2-7190505 FAX: 886-2-7197502

Winbond Electronics (H.K.) Ltd.

Rm. 803, World Trade Square, Tower II, 123 Hoi Bun Rd., Kwun Tong, Kowloon, Hong Kong TEL: 852-27516023 FAX: 852-27552064 Winbond Electronics North America Corp. Winbond Memory Lab. Winbond Microelectronics Corp. Winbond Systems Lab.

2730 Orchard Parkway, San Jose,

CA 95134, U.S.A. TEL: 1-408-9436666 FAX: 1-408-9436668

Note: All data and specifications are subject to change without notice.